MOSPEC

FRF2020K

Switchmode
Full Plastic Dual Schottky Barrier Power Rectifiers

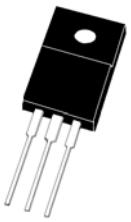
Designed for use in switching power supplies. inverters and as free wheeling diodes. These state-of-the-art devices have the following features:

- ∗Glass Passivated chip junctions
- ∗Low Reverse Leakage Current
- ∗Fast Switching for High Efficiency
- ∗150℃ Operating Junction Temperature
- ∗Low Stored Charge Majority Carrier Conduction
- ∗Low Forward Voltage , High Current Capability
- ∗Plastic Material used Carries Underwriters Laboratory Flammability Classification 94V-O

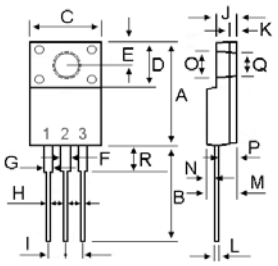
∗*In compliance with EU RoHs 2002/95/EC directives*

FAST RECOVERY RECTIFIERS

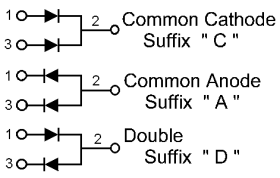
20 AMPERES
200 VOLTS



ITO-220AB



DIM	MILLIMETERS	
	MIN	MAX
A	14.90	15.15
B	13.35	13.55
C	10.00	10.10
D	6.55	6.65
E	2.65	2.75
F	1.55	1.65
G	1.15	1.25
H	0.55	0.65
I	2.50	2.60
J	3.00	3.20
K	1.10	1.20
L	0.55	0.65
M	4.40	4.60
N	1.15	1.25
O	3.35	3.45
P	2.65	2.75
Q	3.15	3.25
R	3.60	3.80



MAXIMUM RATINGS

Characteristic	Symbol	FRF2020K	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	200	V
RMS Reverse Voltage	$V_{R(RMS)}$	140	V
Average Rectifier Forward Current (per diode) Total Device (Rated V_R),T_C=100℃	$I_{F(AV)}$	10 20	A
Peak Repetitive Forward Current (Rate V_R, Square Wave, 20kHz)	I_{FM}	20	A
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware, single phase, 60Hz)	I_{FSM}	150	A
Operating and Storage Junction Temperature Range	T_J , T_{stg}	-65 to +150	℃

ELECTRIAL CHARACTERISTICS

Characteristic	Symbol	FRF2020K	Unit
Maximum Instantaneous Forward Voltage (I_F =10 Amp T_C = 25℃)	V_F	1.15	V
Maximum Instantaneous Reverse Current (Rated DC Voltage, T_C = 25℃) (Rated DC Voltage, T_C = 125℃)	I_R	1 100	uA
Typical Thermal Resistance junction to case	$R_{\theta j\text{-}c}$	3.8	℃/w
Reverse Recovery Time (I_F = 0.5 A, I_R =1.0 , I_{rr} =0.25 A)	T_{rr}	150	ns
Typical Junction Capacitance (Reverse Voltage of 4 volts & f=1 MHz)	C_P	55	pF

FRF2020K

FIG-1 TYPICAL FORWARD CHARACTERISITICS

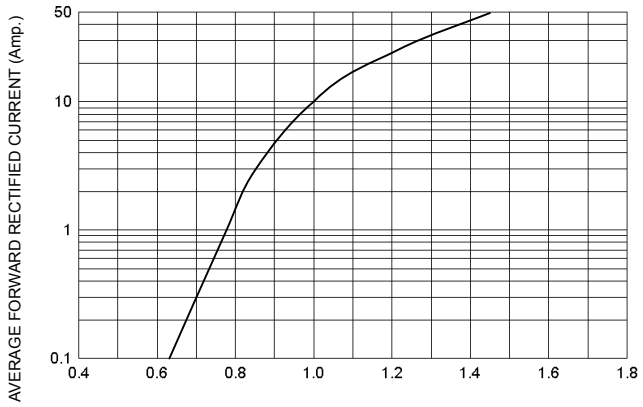


FIG-2 TYPICAL REVERSE CHARACTERISTICS

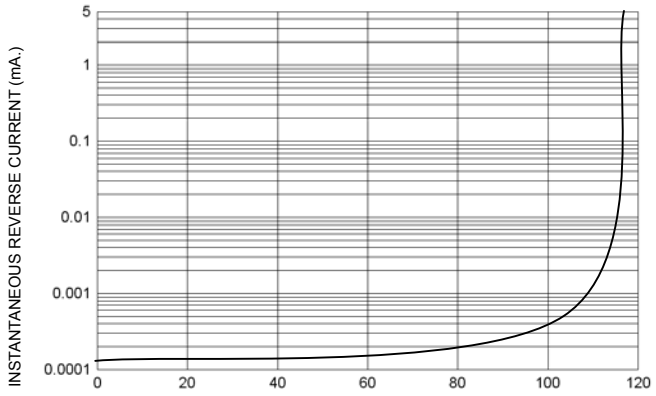


FIG-3 FORWARD CURRENT DERATING CURVE

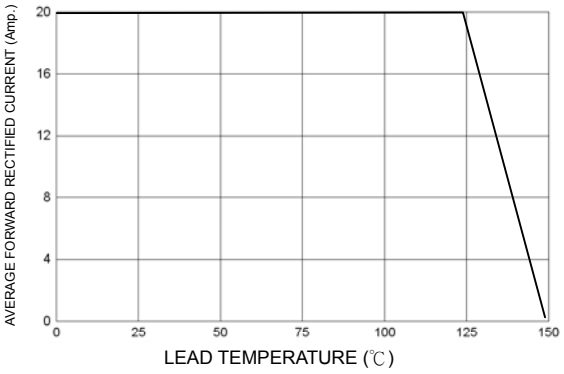


FIG-4TYPICAL JUNCTION CAPACITANCE

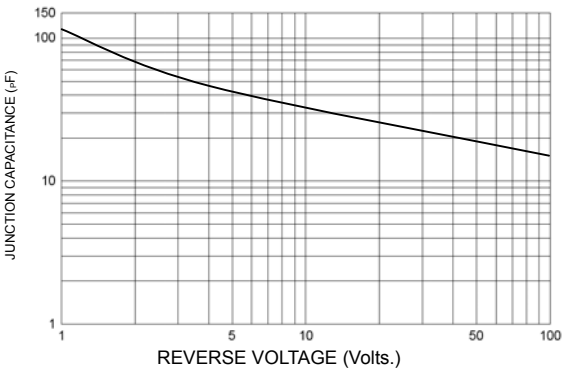
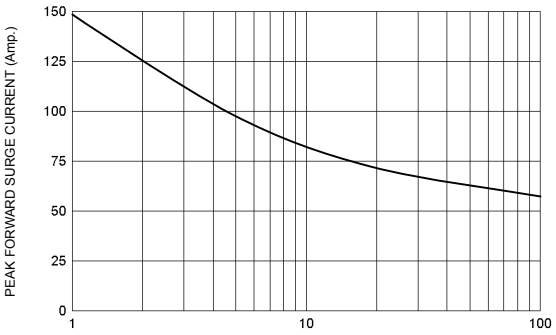
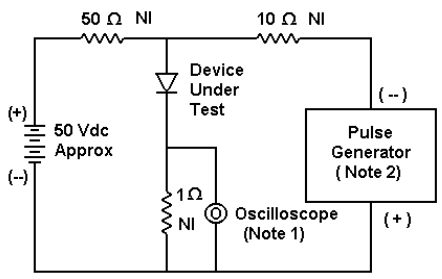
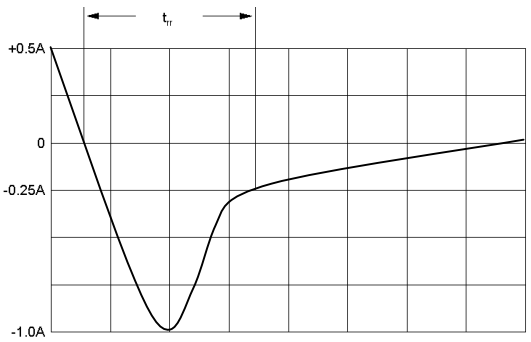


FIG-5 PEAK FORWARD SURGE CURRENT





Notes:
1. Rise Time = 7 ns max. Input Impedance =1 M Ω , 22 pF
2. Rise Time = 10 ns max. Input Impedance = 50 Ω



Set time base for 20/50 ns/cm

FIG-6 Reverse Recovery Time Characteristic and Test Circuit Diagram

Notice

MOSPEC reserves the rights to make changes of the content herein the document anytime without notification. MOSPEC or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies. Please refer to MOSPEC website for the last document.

MOSPEC disclaims any and all liability arising out of the application or use of any product including damages incidentally and consequentially incurred.

Application shown on the herein document are examples of standard use and operation. Customers are responsible for comprehending suitable use in particular applications. MOSPEC makes no representation or warranty that such application will be suitable for the specified use without further testing or modification.

The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by MOSPEC for any infringements of patents or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of MOSPEC or others.

These MOSPEC products are intended for usage in general electronic equipment. Please make sure to consult with MOSPEC before you use these MOSPEC products in equipment which require specialized quality and/or reliability, and in equipment which could have major impact to the welfare of human life (atomic energy control, aeronautics , traffic control, combustion control, safety devices etc.)